NSN 5961-01-052-9593

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-052-9593 **Inclosure Material:** Metal **Overall Length:** 1.266 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 5.00 amperes forward current, total rms nanoamperes **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 2 unthreaded hole and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: